论文

无机EL显示器件用高性能介电层的研究

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摘要 用rf和反应磁控溅射法成功制备了一种总厚度为530~730nm的SrTiO $_3$ /Ta $_2$ O $_5$ 复合介电层,获得在500Hz下介电常数为48~73,反映介电损耗的参数 Δ Vy在0.06~0.15V之间,击穿场强为106~139MV/m,在0.05V/nm的电场下正、反向漏电流在10⁻⁹~10⁻⁷ A/cm 2 之间,品质因子($\varepsilon_r \varepsilon_o E_b$)大于

5μc/cm²。同时比较了SrTiO3/Ta2O5复合介电层和SrTiO₃和Ta₂O₅

单层薄膜的介电性能。把复合膜应用于以 $ZnS:MnnZn_2Si_{0.5}Ge_{0.5}O_4:Mn$ 为发光材料的器件中,获得了适当的阈值电压和较高的亮度。

关键词 无机EL SrTiO3薄膜 Ta2O5薄膜 SrTiO3/Ta2O5复合膜

分类号 TN104.3

High performance dielectric layer for inorganic thin film electroluminescent devices

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Abstract SrTiO3/Ta2O5 doubly stacked dielectric layers with a total thickness of 530 nm to 730 nm were prepared by rf and dc reactive magnetron sputtering. The relative dielectric constant was measured to be 48 to 73 and the Δ Vy which reflects the loss tangent ranges from 0.06 V to 0.15 V at 500 Hz. The breakdown field strength is between 106 MV/m and 139 MV/m. The forward and reverse leakage current density is between 10⁻⁹ A/cm2 and 10⁻⁷ A/cm² at an applied field of 0.05 V/nm, and the figure of merit is higher than 5 μ c/cm². The dielectric properties of the doubly stacked dielectric layers are also compared with single SrTiO₃ and Ta₂O₅ thin films. The doubly stacked dielectric layers were applied to the inorganic TFEL devices with ZnS: Mn and Zn₂Si_{0.5}Ge_{0.5}O₄:Mn thin film phosphor.And suitable threshold voltage and high luminance are achieved.

Key words inorganic EL SrTiO3 thin film Ta2O5 thin film SrTiO3/Ta2O5 stacked layer

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扩展功能

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